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layer of resin over said cell except for the positive and negative output terminals thereof.

20. A method of manufacturing a solar cell according to claim 1, wherein the powdered raw materials for the layers of n-type and p-type semiconductors comprise elements of groups II and VI or a compound thereof. 5

21. A method of manufacturing a solar cell according to claim 20, further comprising a step of forming a passivation layer of resin over said cell except for the positive and negative output terminals thereof. 10

22. A method a manufacturing a solar cell according to claim 1, wherein said n-type compound semiconductor layer

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comprises CdS, and said p-type compound semiconductor layer comprises one of CdTe and CuInSe<sub>2</sub>.

23. A method of manufacturing a solar cell according to claim 22, further comprising a step of forming a passivation layer of resin over said cell except for the positive and negative output terminals thereof.

24. A method of manufacturing a solar cell according to claim 1, further comprising a step of forming a passivation layer of resin over said cell except for the positive and negative output terminals thereof.

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